SWITCHMODE™ Power Rectifier 45 V, 60 A

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 60 A Total (30 A Per Diode Leg)
- Guard-Ring for Stress Protection

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220) 4.3 Grams (TO-247)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube for TO-220 and 30 Units Per Plastic Tube for TO-247
- This is a Pb-Free Device

MAXIMUM RATINGS

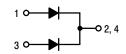
Please See the Table on the Following Page

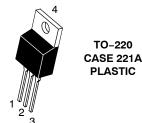


ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER **RECTIFIERS 60 AMPERES, 45 VOLTS**

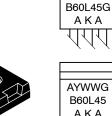






AKA

AKA





B60L45 = Device Code = Assembly Location

PLASTIC

= Year WW = Work Week AKA = Polarity Designator = Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping
MBR60L45CTG	TO-220 (Pb-Free)	50 Units/Rail
MBR60L45WTG	TO-247 (Pb-Free)	30 Units/Rail

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MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V_R) T_C = 145°C for MBR60L45CTG (Rated V_R) T_C = 165°C for MBR60L45WTG	I _{F(AV)}	30	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz)	I _{FRM}	60	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	200	Α
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Storage Temperature	T _{stg}	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V
HERMAL CHARACTERISTICS			
Maximum Thermal Resistance (MBR60L45CTG) - Junction-to-Case (MBR60L45WTG) - Junction-to-Case	R _{θJC} R _{θJC}	1.9 0.59	°C/W
ELECTRICAL CHARACTERISTICS (Per Diode Leg)		_	•
Maximum Instantaneous Forward Voltage (Note 2) $ \begin{aligned} &(I_F=30~A,~T_C=25^\circ\text{C})\\ &(I_F=30~A,~T_C=125^\circ\text{C})\\ &(I_F=60~A,~T_C=25^\circ\text{C})\\ &(I_F=60~A,~T_C=125^\circ\text{C}) \end{aligned} $	V _F	0.55 0.53 0.73 0.76	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, T _C = 25°C)	i _R	1.2	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect

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- The heat generated must be less than the thermal conductivity from Junction–to–Ambient: dP_D/dT_J < 1/R_{θJA}.
 Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤[2.0%.

(Rated DC Voltage, T_C = 125°C)

TYPICAL CHARACTERISTICS

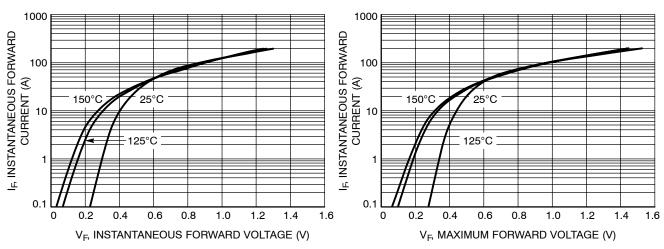


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

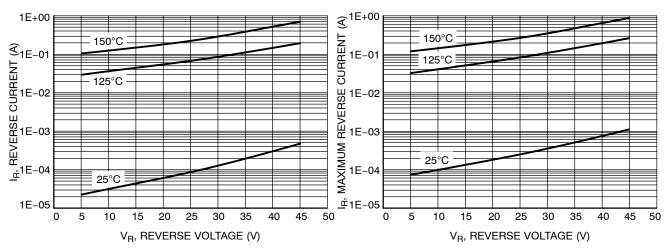


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

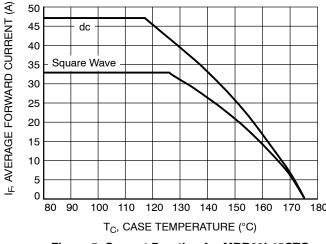


Figure 5. Current Derating for MBR60L45CTG

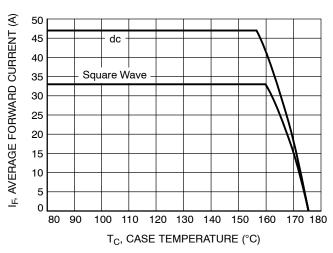


Figure 6. Current Derating for MBR60L45WTG

TYPICAL CHARACTERISTICS

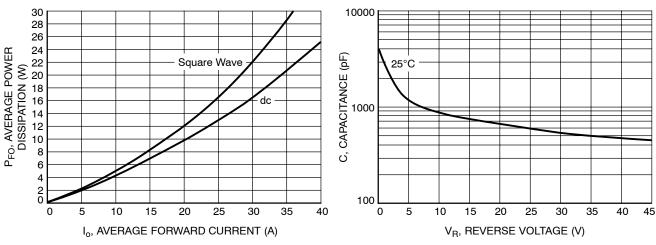


Figure 7. Forward Power Dissipation

Figure 8. Capacitance

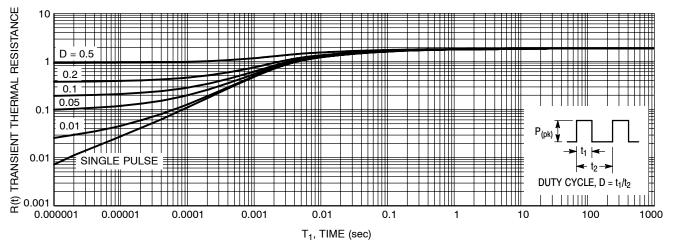


Figure 9. Thermal Response Junction-to-Case for MBR60L45CTG

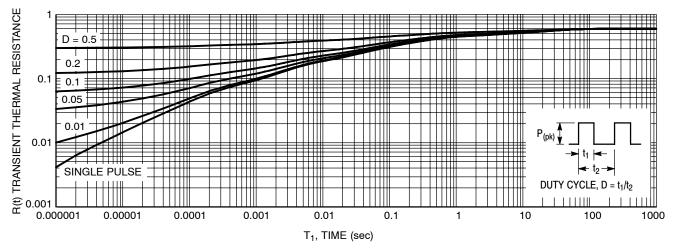
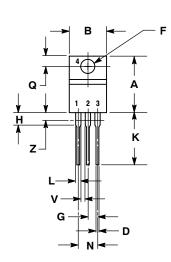
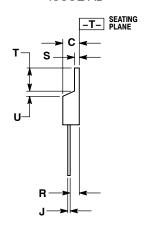


Figure 10. Thermal Response Junction-to-Case for MBR60L45WTG

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AD**



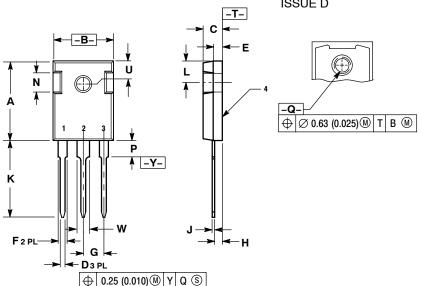


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

TO-247 CASE 340L-02 ISSUE D



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	20.32	21.08	0.800	8.30
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
Е	2.20	2.60	0.087	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
Н	1.50	2.49	0.059	0.098
L	0.40	0.80	0.016	0.031
Κ	20.06	20.83	0.790	0.820
٦	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
Р		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

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